

WHAT IS CLAIMED IS:

1. A liquid crystal display device, comprising:

at least two storage capacitors disposed between a gate line and a capacitor electrode, said gate line being connected, via a contact hole passing through said at least two storage capacitors, to the capacitor electrode.

2. The liquid crystal display device as claimed in claim 1, wherein the capacitor electrode is made from a transparent conductive material selected from the group consisting of indium-tin-oxide, indium-zinc-oxide and indium-tin-zinc-oxide.

3. The liquid crystal display device as claimed in claim 1, further comprising:

a gate insulating film provided on a substrate;

a storage electrode provided on the gate insulating film; and

a protective layer provided between the storage electrode and the capacitor electrode.

4. The liquid crystal display device as claimed in claim 3, wherein the storage capacitor includes:

a first storage capacitor provided between the storage electrode and the gate line with the intervening gate insulating film; and

a second storage capacitor provided between the storage electrode and the capacitor electrode with the intervening protective layer.

5. The liquid crystal display device as claimed in claim 4, wherein the first storage capacitor is connected to the second storage capacitor in parallel.

6. The liquid crystal display device as claimed in claim 4, wherein the contact hole is at least two holes spaced to each other at a length larger than the width of the storage electrode.

7. The liquid crystal display device as claimed in claim 6, wherein the capacitor electrode has a length larger than the storage electrode.

8. The liquid crystal display device as claimed in claim 3, further comprising:

a gate electrode connected to the gate line;
source and drain electrodes provided on the gate insulating film; and
a pixel electrode provided on the protective layer to be electrically connected to the drain electrode.

9. The liquid crystal display device as claimed in claim 3, wherein the pixel electrode electrically contacts the storage electrode through said contact hole passing through the protective layer.

10. The liquid crystal display device as claimed in claim 8, wherein the gate insulating film has a thickness of about 4000Å.

11. The liquid crystal display device as claimed in claim 8, wherein the protective layer has a thickness of about 2000Å.

12. A method of fabricating a liquid crystal display device, comprising the steps of:

forming a gate line on a substrate;

forming a gate insulating film on the substrate;

forming a storage electrode on the gate insulating film;

forming a protective layer on the gate insulating film;

defining at least two contact holes to expose the gate line; and

forming a capacitor electrode electrically contacting the gate line on the protective layer.

13. The method as claimed in claim 12, wherein the capacitor electrode is made from a transparent conductive material selected from the group consisting of indium-tin-oxide, indium-zinc-oxide and indium-tin-

zinc-oxide.

14. The method as claimed in claim 12, wherein the said least two contact holes are spaced to each other at a length larger than the width of the storage electrode.

15. The method as claimed in claim 14, wherein the capacitor electrode has a length larger than the storage electrode.

16. The method as claimed in claim 12, further comprising the steps of:

- forming a gate electrode connected to the gate line on the substrate;
- forming a semiconductor layer on the gate insulating film;
- forming source and drain electrodes on the semiconductor layer; and
- forming a pixel electrode on the protective layer.

17. The method as claimed in claim 16, wherein the pixel electrode electrically contacts the storage electrode through said contact hole passing through the protective layer.

18. The method as claimed in claim 16, wherein the gate insulating film has a thickness of about 4000Å.

19. The method as claimed in claim 16, wherein the protective layer has a thickness of about 2000Å.